Power MOSFET 8 V, ±3.3 A, Load Switch with Level–Shift, P–Channel, TSOP–6

The NTGD1100L integrates a P and N–Channel MOSFET in a single package. This device is particularly suited for portable electronic equipment where low control signals, low battery voltages and high load currents are needed. The P–Channel device is specifically designed as a load switch using ON Semiconductor state–of–the–arttrench technology. The N–Channel, with an external resistor (R1), functions as a level–shift to drive the P–Channel. The N–Channel MOSFET has internal ESD protection and can be driven by logic signals as low as 1.5 V. The NTGD1100L operates on supply lines from 1.8 to 8.0 V and can drive loads up to 3.3 A with 8.0 V applied to both V_{IN} and $V_{ON/OFF}$

Features

- Extremely Low RDS(on) Load Switch MOSFET
- Level Shift MOSFET is ESD Protected
- Low Profile, Small Footprint Package
- V_{IN} Range 1.8 to 8.0 V
- ON/OFF Range 1.5 to 8.0 V
- ESD Rating of 3000 V
- Pb-Free Package is Available

MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

Rating	Symbol	Value	Unit		
Input Voltage (V _{DSS} , P-Cl	V _{IN}	8.0	V		
ON/OFF Voltage (V _{GS} , N-	-Ch)		V _{ON/OFF}	8.0	V
Continuous Load Current			١L	±3.3	А
(Note 1)	State	T _A = 85°C		±2.4	
Power Dissipation	Steady	$T_A = 25^{\circ}C$	PD	0.83	W
(Note 1)	State	T _A = 85°C		0.43	
Pulsed Load Current	tp =	10 μs	I _{LM}	±10	А
Operating Junction and St	T _J , T _{STG}	–55 to 150	°C		
Source Current (Body Dio	de)		I _S	-1.0	А
ESD Rating, MIL-STD-88 (100 pF, 1.5 kΩ)	ESD	3.0	kV		
Lead Temperature for Sold (1/8" from case for 10 s)	ΤL	260	°C		

THERMAL RESISTANCE RATINGS

Rating	Symbol	Max	Unit
Junction-to-Ambient - Steady State (Note 1)	$R_{\mu JA}$	150	°C/W
Junction-to-Foot - Steady State (Note 1)	$R_{\mu JF}$	50	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Surface-mounted on FR4 board using 1 in sq pad size

(Cu area = 1.127 in sq [1 oz] including traces).

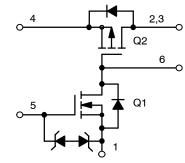


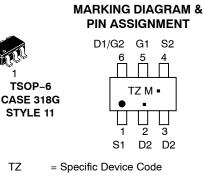
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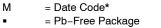
http://onsemi.com

V _{(BR)DSS} R _{DS(on)} TYP		I _D MAX
8.0 V	40 mΩ @ -4.5 V	
	55 mΩ @ –2.5 V	±3.3 A
	80 mΩ @ –1.8 V	

SIMPLIFIED SCHEMATIC







(Note: Microdot may be in either location) *Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]		
NTGD1100LT1	TSOP-6	3000/Tape & Reel		
NTGD1100LT1G	TSOP-6 (Pb-Free)	3000/Tape & Reel		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted)

Q2 Drain-to-Source On Resistance

Load Current

Characteristic	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS		•			•		
Q2 Drain-to-Source Breakdown Voltage	V _{IN}	$V_{GS2} = 0 V, I_{D2}$	<u>e</u> = 250 μA	8.0			V
Forward Leakage Current	I _{FL}	$V_{GS2} = 0 V$, $T_{J} = 25^{\circ}C$				1.0	μΑ
		$V_{DS2} = 8.0 V$	T _J = 125°C			10	1
Q1 Gate-to-Source Leakage Current	I _{GSS}	V _{DS1} = 0 V, V _{GS1} = ±8.0 V				±100	nA
Q1 Diode Forward On-Voltage	V _{SD}	I _S = -1.0 A, V _{GS1} = 0 V			-0.7	-1.0	V
ON CHARACTERISTICS							
Voltage ON/OFF	V _{ON/OFF}			1.5		8.0	V
Q1 Gate Threshold Voltage	V _{GS1}	$V_{GS1} = V_{DS1}, I_D = 50 \ \mu A$		0.6		1.2	V
Input Voltage	V _{IN}	$V_{GS2} = V_{DS2}, I_D = 250 \ \mu A$		1.8		8.0	V

 $\begin{array}{l} V_{ON/OFF} = 1.5 \text{ V}, \\ I_L = 1.0 \text{ A} \end{array}$

 $V_{DROP} \le 0.2 \text{ V}, V_{IN} = 5.0 \text{ V}, \\ V_{ON/OFF} = 1.5 \text{ V}$

 $\label{eq:VDROP} \begin{array}{l} V_{\text{DROP}} \leq 0.2 \text{ V}, \ V_{\text{IN}} = 2.5 \text{ V}, \\ V_{\text{ON/OFF}} = 1.5 \text{ V} \end{array}$

 $\label{eq:VDROP} \begin{array}{l} V_{DROP} \leq 0.2 \ V, \ V_{IN} = 1.8 \ V, \\ V_{ON/OFF} = 1.5 \ V \end{array}$

V_{IN} = 4.5 V

 $V_{IN} = 2.5 V$

V_{IN} = 1.8 V

40

55

80

1.0

1.0

1.0

55

70

140

mΩ

А

R_{DS(on)}

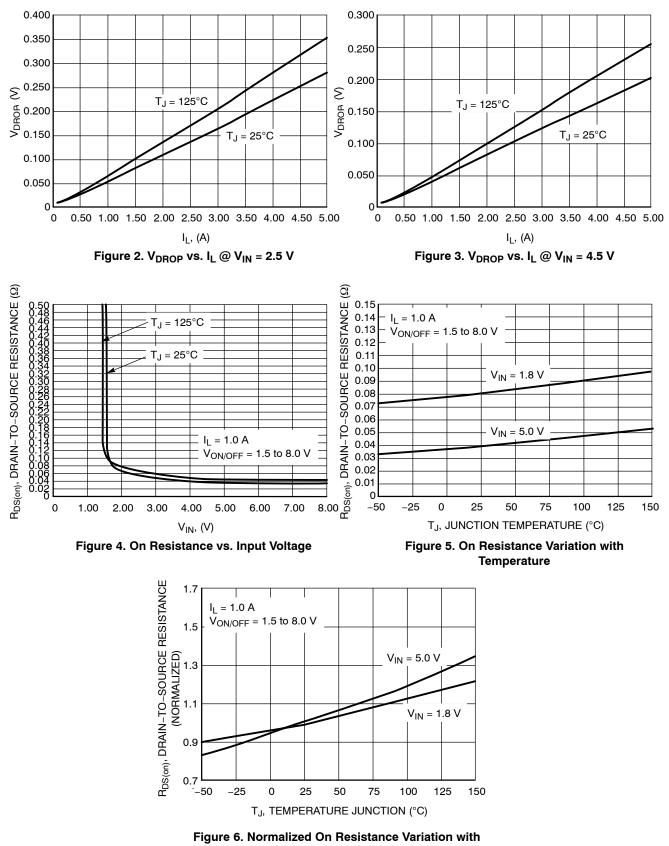
 $I_{\rm L}$

V _{IN} O R1	4		2,3	C 1	-O V _{OUT}
on/off o	5		_	;₀ <u> </u>	LOAD
C ₁ =	 	1	2		O GND



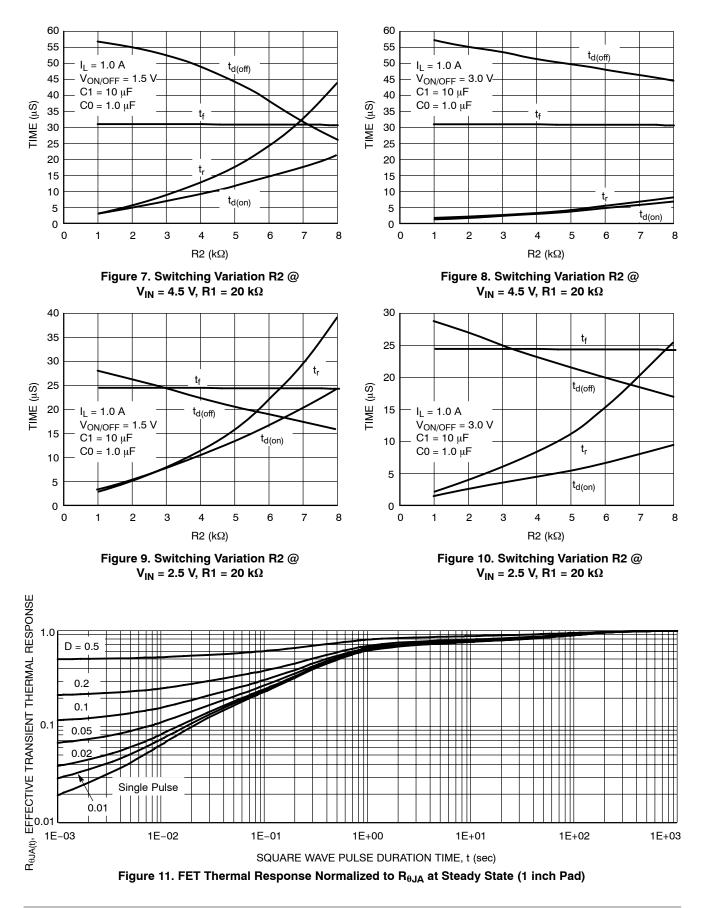
Components	Description	Values	
R1	Pullup Resistor	Typical 10 k Ω to 1.0 M Ω	
R2	Optional Slew-Rate Control	Typical 0 to 100 k Ω	
C0	Output Capacitance	Usually < 1.0 μF	
C1	Optional In-Rush Current Control	Typical ≤ 1000 pF	

TYPICAL CHARACTERISTICS



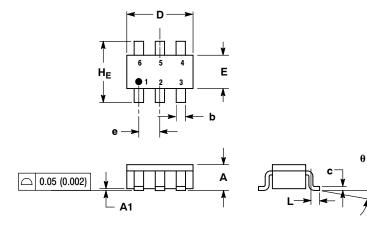
Temperature

TYPICAL CHARACTERISTICS



PACKAGE DIMENSIONS

TSOP-6 CASE 318G-02 ISSUE P



NOTES

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2
- CONTROLLING DIMENSION: MILLIMETER. MAXIMUM LEAD THICKNESS INCLUDES LEAD 3. FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF
- BASE MATERIAL DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE 4. BURRS.

	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.90	1.00	1.10	0.035	0.039	0.043	
A1	0.01	0.06	0.10	0.001	0.002	0.004	
b	0.25	0.38	0.50	0.010	0.014	0.020	
С	0.10	0.18	0.26	0.004	0.007	0.010	
D	2.90	3.00	3.10	0.114	0.118	0.122	
E	1.30	1.50	1.70	0.051	0.059	0.067	
е	0.85	0.95	1.05	0.034	0.037	0.041	
L	0.20	0.40	0.60	0.008	0.016	0.024	
HE	2.50	2.75	3.00	0.099	0.108	0.118	
θ	0°	-	10°	0°	-	10°	

STYLE 11:

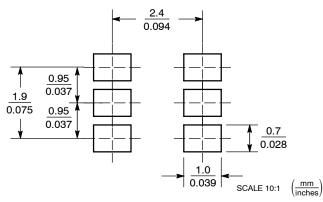
PIN 1. SOURCE 1 2. DRAIN 2

3. DRAIN 2

4. SOURCE 2

5. GATE 1 6. DRAIN 1/GATE 2

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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